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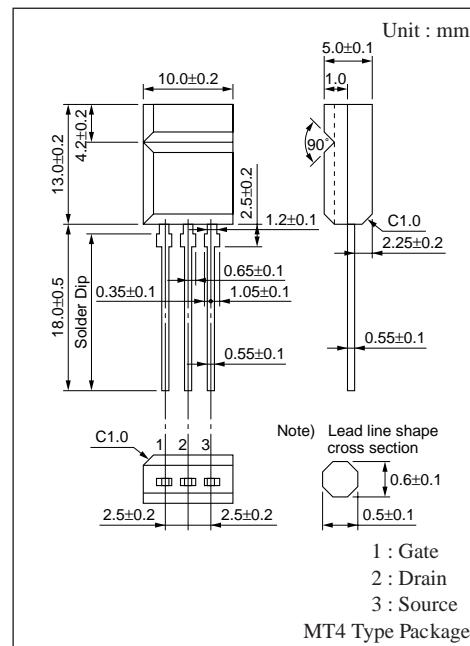
Silicon N-Channel Power F-MOS

■ Features

- Avalanche energy capability guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown
- Low-voltage drive
- Radial taping possible

■ Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator



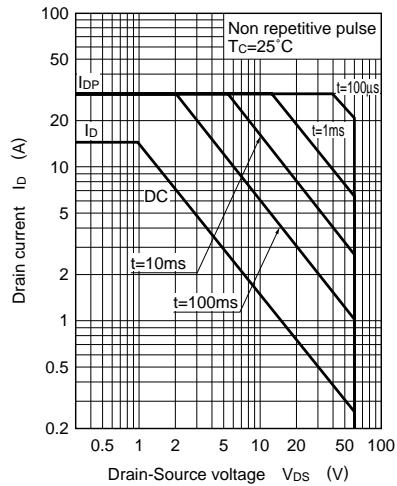
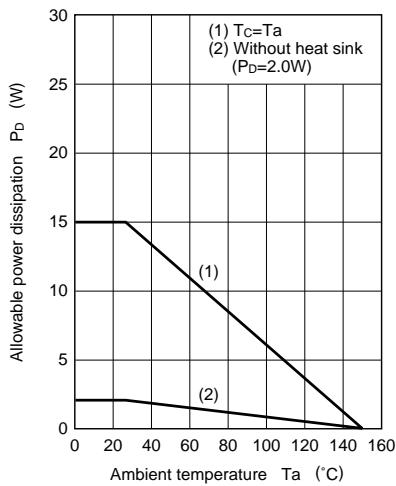
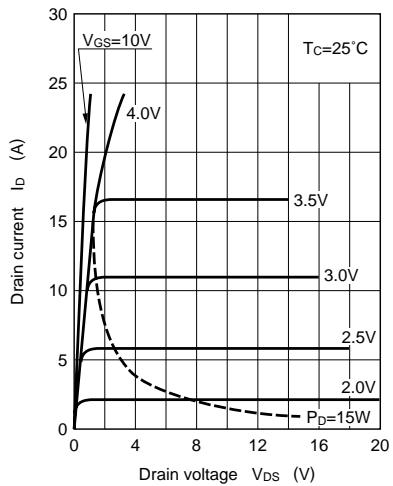
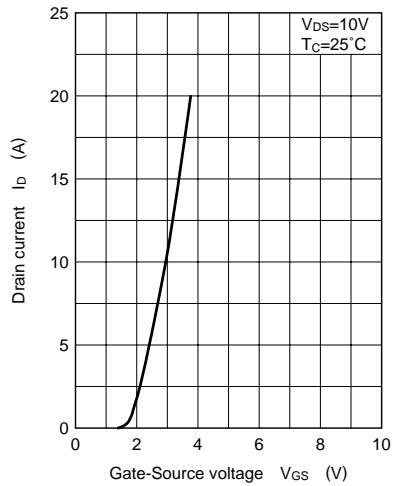
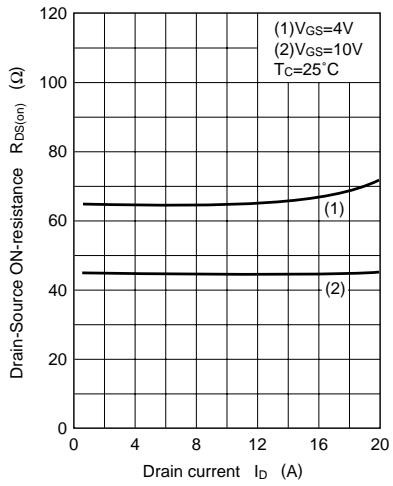
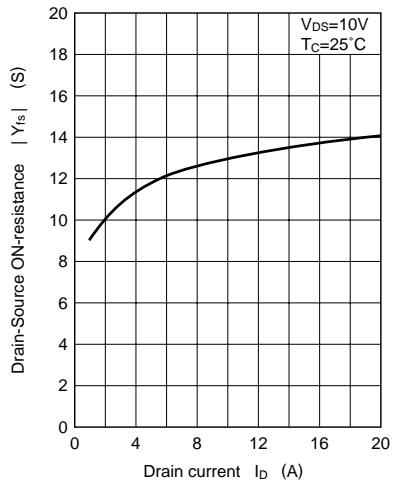
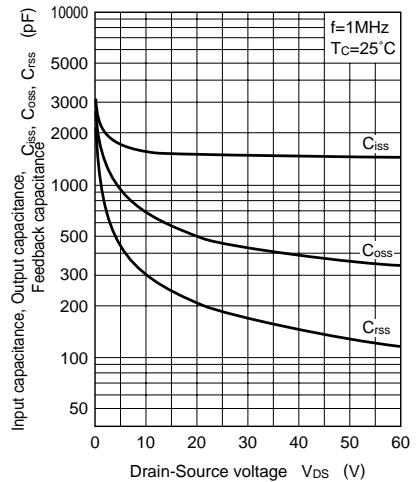
■ Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Drain-Source breakdown voltage	V_{DSS}	60	V
Gate-Source voltage	V_{GSS}	± 20	V
Drain current	DC I_D	± 15	A
	Pulse I_{DP}	± 30	A
Allowable power dissipation	$T_C = 25^\circ\text{C}$ P_D	15	W
	$T_a = 25^\circ\text{C}$	2	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

■ Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source cut-off current	I_{DSS}	$V_{DS}=40\text{V}, V_{GS}=0$			10	μA
Gate-Source leakage current	I_{GSS}	$V_{GS}=\pm 20\text{V}, V_{DS}=0$			± 1	μA
Drain-Source breakdown voltage	V_{DSS}	$I_D=1\text{mA}, V_{GS}=0$	60			V
Gate threshold voltage	V_{th}	$V_{DS}=10\text{V}, I_D=1\text{mA}$	1		2.5	V
Drain-Source ON-resistance	$R_{DS(on)1}$	$V_{GS}=10\text{V}, I_D=10\text{A}$		45	70	$\text{m}\Omega$
	$R_{DS(on)2}$	$V_{GS}=4\text{V}, I_D=6\text{A}$		65	100	$\text{m}\Omega$
Forward transadmittance	$ Y_{fs} $	$V_{DS}=10\text{V}, I_D=10\text{A}$	8	13		S
Diode forward voltage	V_{DSF}	$I_{DR}=10\text{A}, V_{GS}=0$			-1.7	V
Input capacitance	C_{iss}	$V_{DS}=10\text{V}, V_{GS}=0, f=1\text{MHz}$		1550		pF
Output capacitance	C_{oss}			680		pF
Feedback capacitance	C_{rss}			300		pF
Turn-on time	t_{on}	$V_{DD}=30\text{V}, I_D=10\text{A}$ $V_{GS}=10\text{V}, R_L=3\Omega$		90		ns
Fall time	t_f			180		ns
Turn-off time (delay time)	$t_{d(off)}$			360		ns
Channel-Case heat resistance	$R_{th(ch-c)}$				8.33	$^\circ\text{C}/\text{W}$
Channel-Atmosphere heat resistance	$R_{th(ch-a)}$				62.5	$^\circ\text{C}/\text{W}$

Area of safe operation (ASO)

P_D – TaI_D – V_{GS}R_{DS(on)} – I_DR_{DS(on)} – I_D|Y_{fs}| – I_DC_{iss}, C_{oss}, C_{rss} – V_{DS}t_{on}, t_f, t_{d(off)} – I_D